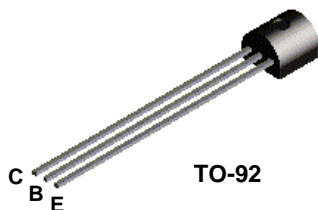
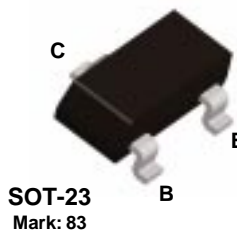


2N4400



MMBT4400



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CB0}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector Current - Continuous	600	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		2N4400	*MMBT4400	
P _D	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3		°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	200	357	°C/W

NPN General Purpose Amplifier

(continued)

2N4400 / MMBT4400

Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
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OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 1.0 \text{ mA}, I_B = 0$	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 100 \text{ } \mu\text{A}, I_E = 0$	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 100 \text{ } \mu\text{A}, I_C = 0$	6.0		V
I_{CEX}	Collector Cutoff Current	$V_{CE} = 35 \text{ V}, V_{EB} = 0.4 \text{ V}$		0.1	μA
I_{BL}	Emitter Cutoff Current	$V_{CE} = 35 \text{ V}, V_{EB} = 0.4 \text{ V}$		0.1	μA

ON CHARACTERISTICS*

h_{FE}	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_C = 1.0 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_C = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_C = 150 \text{ mA}$ $V_{CE} = 2.0 \text{ V}, I_C = 500 \text{ mA}$	20 40 50 20	150	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.40 0.75	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$	0.75	0.95 1.2	V

SMALL SIGNAL CHARACTERISTICS

C_{ob}	Output Capacitance	$V_{CB} = 5.0 \text{ V}, f = 140 \text{ kHz}$		6.5	pF
C_{ib}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, f = 140 \text{ kHz}$		30	pF
h_{fe}	Small-Signal Current Gain	$I_C = 20 \text{ mA}, V_{CE} = 10 \text{ V},$ $f = 100 \text{ MHz}$	2.0		
h_{fe}	Small-Signal Current Gain	$V_{CE} = 10 \text{ V}, I_C = 1.0 \text{ mA},$ $f = 1.0 \text{ kHz}$	20	250	
h_{ie}	Input Impedance	$f = 1.0 \text{ kHz}$	0.5	7.5	$\text{K}\Omega$
h_{re}	Voltage Feedback Ratio		0.1	8.0	$\times 10^{-4}$
h_{oe}	Output Admittance		1.0	30	μmhos

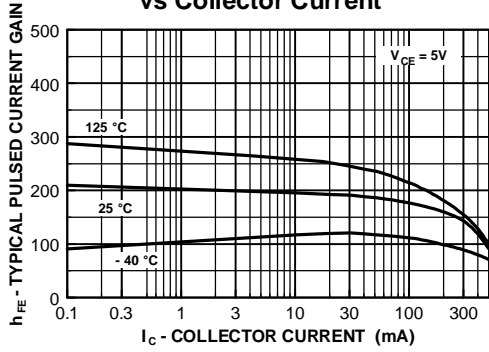
SWITCHING CHARACTERISTICS

t_d	Delay Time	$V_{CC} = 30 \text{ V}, I_C = 150 \text{ mA},$		15	ns
t_r	Rise Time	$I_{B1} = 15 \text{ mA}, V_{EB} = 2 \text{ V}$		20	ns
t_s	Storage Time	$V_{CC} = 30 \text{ V}, I_C = 150 \text{ mA}$		225	ns
t_f	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$		30	ns

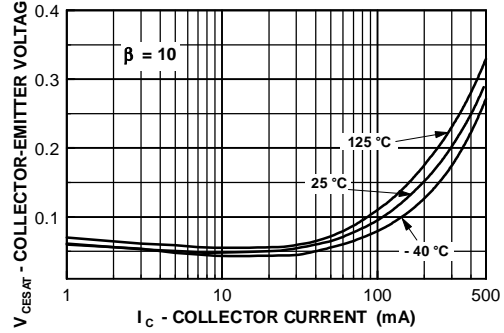
*Pulse Test: Pulse Width $\leq 300 \text{ ms}$, Duty Cycle $\leq 2.0\%$

Typical Characteristics

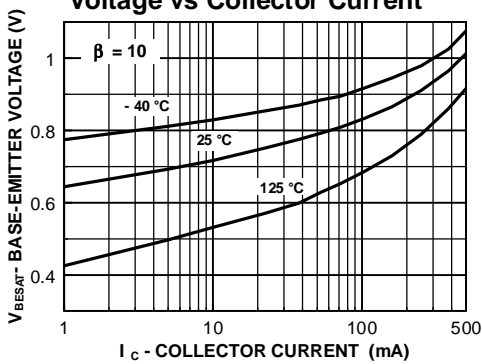
Typical Pulsed Current Gain vs Collector Current



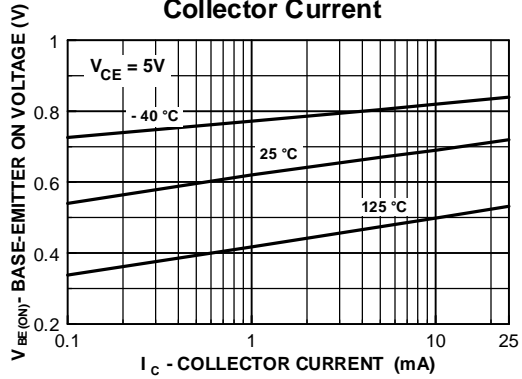
Collector-Emitter Saturation Voltage vs Collector Current



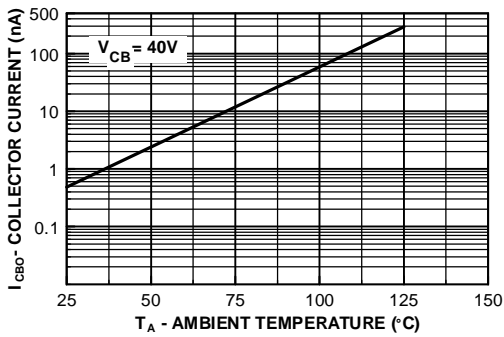
Base-Emitter Saturation Voltage vs Collector Current



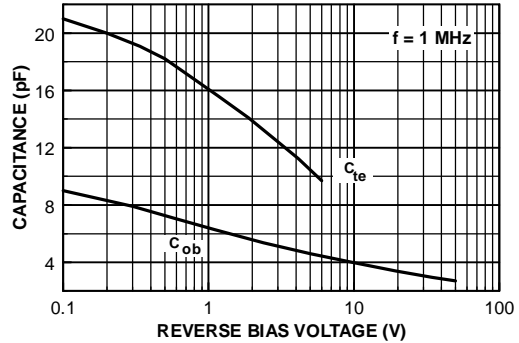
Base-Emitter ON Voltage vs Collector Current



Collector-Cutoff Current vs Ambient Temperature



Emitter Transition and Output Capacitance vs Reverse Bias Voltage



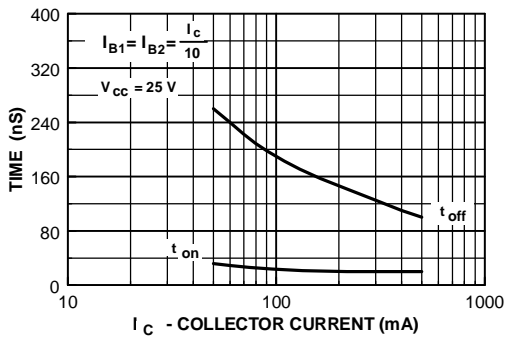
NPN General Purpose Amplifier

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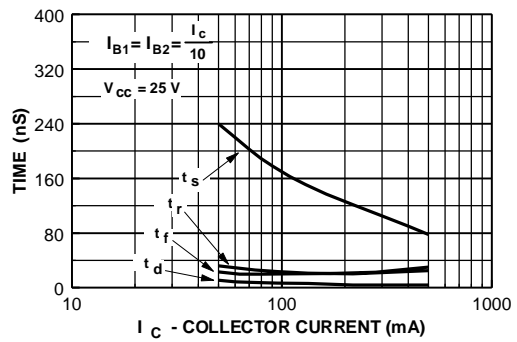
2N4400 / MMBT4400

Typical Characteristics (continued)

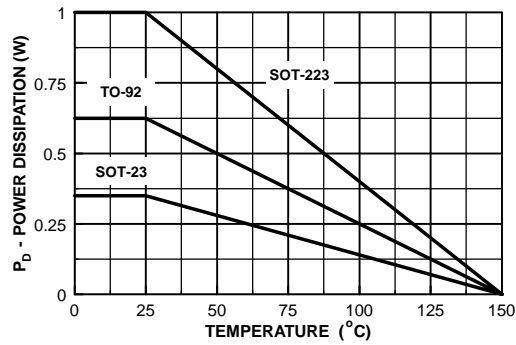
Turn On and Turn Off Times vs Collector Current



Switching Times vs Collector Current



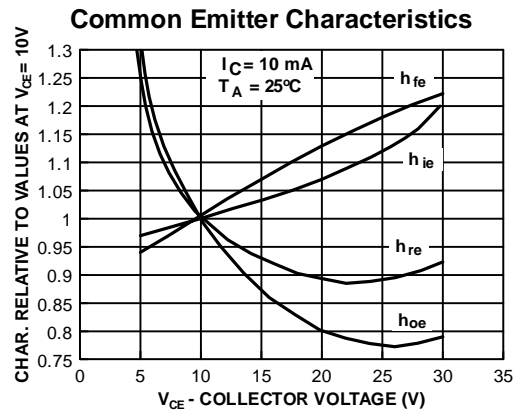
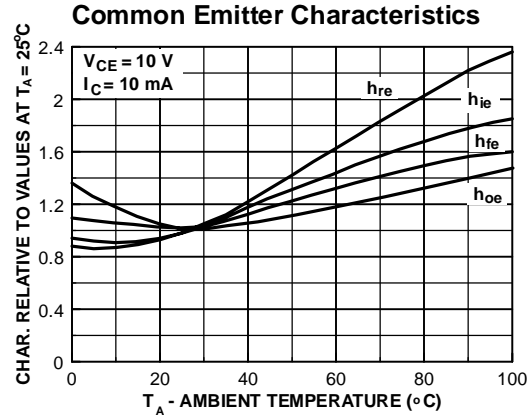
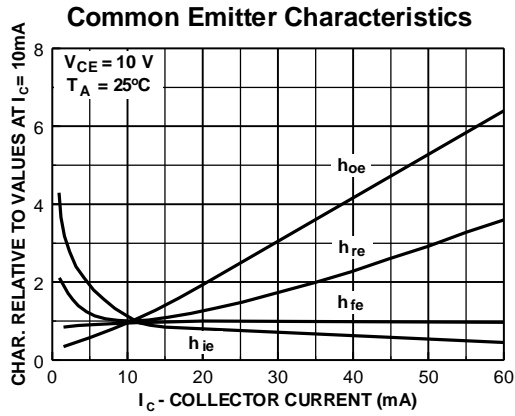
Power Dissipation vs Ambient Temperature



NPN General Purpose Amplifier
(continued)

2N4400 / MMBT4400

Typical Common Emitter Characteristics ($f = 1.0\text{kHz}$)



Test Circuits

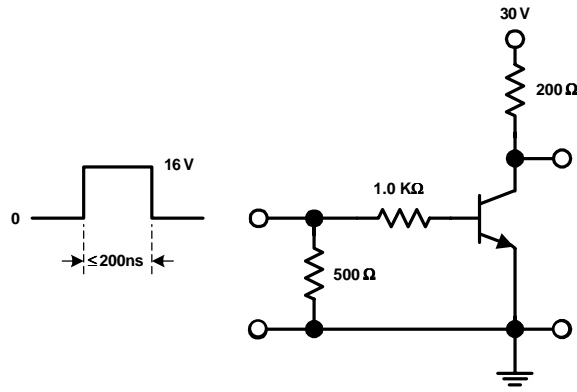


FIGURE 1: Saturated Turn-On Switching Timer

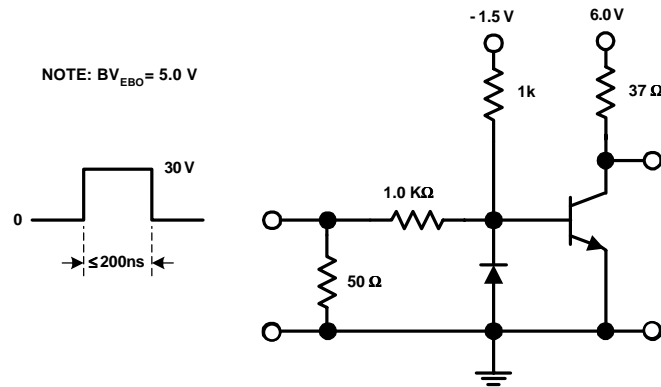


FIGURE 2: Saturated Turn-Off Switching Time

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Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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2N4400

NPN General Purpose Amplifier

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General description

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

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Product status/pricing/packageing

BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
2N4400BU	Full Production	 Full Production	\$0.026	TO-92	3	BULK	Line 1: 2N Line 2: 4400 Line 3: -&3
2N4400TA	Full Production	 Full Production	\$0.026	TO-92	3	AMMO	Line 1: 2N Line 2: 4400 Line 3: -&3
2N4400TAR	Full Production	 Full Production	\$0.026	TO-92	3	AMMO	Line 1: 2N Line 2: 4400 Line 3: -&3
2N4400TF	Full Production		\$0.026	TO-92	3	TAPE REEL	Line 1: 2N Line 2: 4400 Line 3: -&3

BUY

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		 Full Production					
2N4400TFR	Full Production	 Full Production	\$0.026	TO-92	3	TAPE REEL	Line 1: 2N Line 2: 4400 Line 3: -&3
2N4400_D81Z	Full Production	 Full Production	N/A	TO-92	3	TAPE REEL	Line 1: \$Y (Fairchild logo) & Z (Asm. Plant Code) & 3 (3-Digit Date Code) Line 2: 2N Line 3: 4400

* Fairchild 1,000 piece Budgetary Pricing

** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a [Fairchild distributor](#) to obtain samples



Indicates product with Pb-free second-level interconnect. For more information [click here](#).

Package marking information for product 2N4400 is available. [Click here for more information](#).

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Models

Package & leads	Condition	Temperature range	Software version	Revision date
PSPICE				
TO-92-3	Electrical	25°C	N/A	N/A

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Qualification Support

Click on a product for detailed qualification data

Product
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2N4400TA
2N4400TAR
2N4400TF
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